

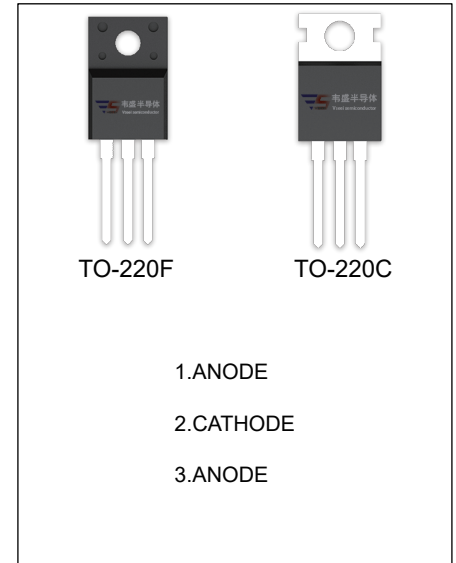
SBD1060CT、SBDF1060CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	10 (2×5) A
V_{RRM}	60V
T_j	150 °C
$V_{F(typ)}$	0.56V (@Tj=125°C)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



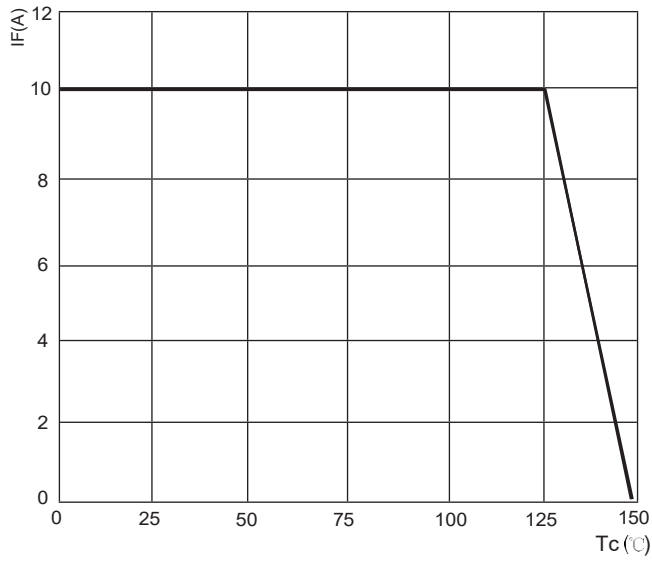
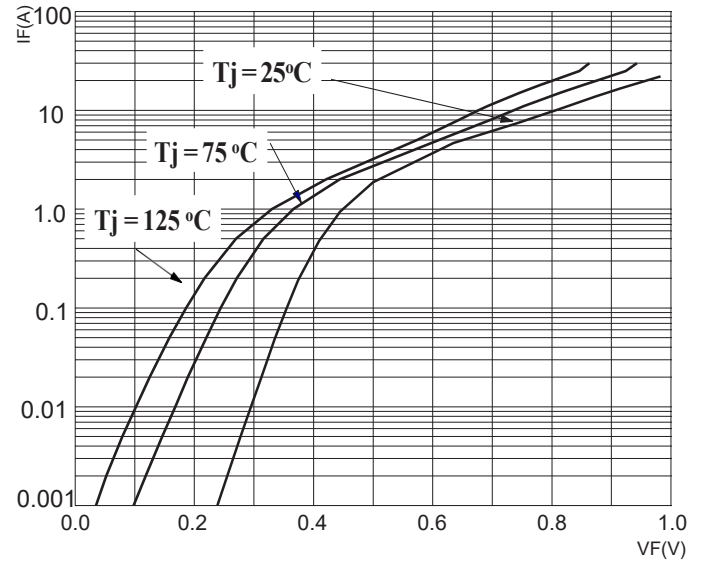
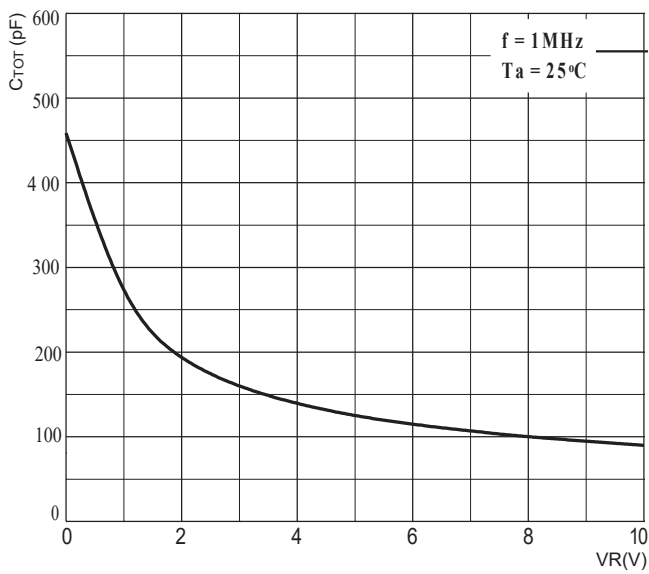
MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	SBD		Unit
		1060CT	F1060CT	
V_{RRM}	Peak repetitive reverse voltage	60		V
V_{RWM}	Working peak reverse voltage			
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	42		V
I_O	Average rectified output current	10		A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	120		A
$R_{\theta Jc}$	Thermal resistance from junction to case ,Tc=25°C	2.0	3.0	°C/W
$R_{\theta JA}$	Thermal resistance from junction to ambient	62.5		°C/W
T_j	Junction temperature	150		°C
T_{stg}	Storage temperature	-55~+150		°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$	60			V
Reverse current	I_R	$V_R=60V$	$T_j=25^{\circ}C$	10	100	uA
			$T_j=125^{\circ}C$	10		mA
Forward voltage	V_F	$I_F=3A$	$T_j=25^{\circ}C$	0.57		V
			$T_j=125^{\circ}C$	0.50		V
		$I_F=5A$	$T_j=25^{\circ}C$	0.67	0.70	V
			$T_j=125^{\circ}C$	0.56		V

*Pulse test: pulse width ≤300μs, duty cycles ≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

FIG.2: TYPICAL FORWARD CHARACTERISTICS

FIG.3: TOTAL CAPACITANCE DERATING CURVE

FIG.4: TYPICAL REVERSE CHARACTERISTICS
